Solutions to  $\it The \ Art \ of \ Electronics \ 3rd \ Edition$ 

February 12, 2024

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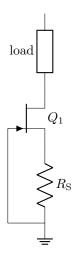
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# Solutions for Chapter 3

## Exercise 3.1

Figure 1.1: JFET current source



From Figure 3.21 of the book, one can see that a drain current equal to  $1\,\mathrm{mA}$  corresponds to a gate-source voltage of  $-0.6\,\mathrm{V}$ . Therefore:

$$R_{\rm S} = \frac{0.6\,\mathrm{V}}{1\,\mathrm{mA}} = 600\,\Omega$$

### Exercise 3.2

At  $V_{\text{GS}} = V_{\text{G0}}$ :

$$r_{\mathrm{GS}} = r_{\mathrm{G0}} = \frac{1}{2k \left( V_{\mathrm{G0}} - V_{\mathrm{th}} \right)}$$

The ratio between  $r_{\rm DS}$  and  $R_{\rm G0}$  returns:

$$\frac{r_{\rm DS}}{r_{\rm G0}} = \frac{2k \left(V_{\rm G0} - V_{\rm th}\right)}{2k \left(V_{\rm GS} - V_{\rm th}\right)}$$

#### Exercise 3.3

Being  $g_{\rm m}$  the differential conductance of the FET operated in aturation region, it can be expressed as:

$$g_{\rm m} = \frac{\partial I_{\rm D}}{\partial V_{\rm GS}} = \frac{\partial}{\partial V_{\rm GS}} k \left( V_{\rm GS} - V_{\rm th} \right)^2 = 2k \left( V_{\rm GS} - V_{\rm th} \right)$$

Therefore:

$$g_{\rm m} = \frac{1}{r_{\rm DS}}$$

#### Exercise 3.4

(a) The voltage across the drain-gate capacitance when the JFET is switched on  $(V_{DS} = 0 \text{ V})$  is equal to 50 V-10 V=40 V. Considering a maximum current across this capacitance equal to 1 mA:

$$t_{
m ON} = rac{40 \, 
m V \, 200 \, pF}{1 \, 
m mA} = 8 \, 
m \mu s$$

(b) Since the current is equal to the charge over time, we have:

$$t_{\rm ON} = \frac{40\,\mathrm{nC}}{1\,\mathrm{mA}} = 40\,\mathrm{\mu s}$$

#### Exercise 3.5

The 1 pF drain-source capacitance happens to be in series with the  $10\,\mathrm{k}\Omega$  load resistance. The capacitive reactance is:

$$X_{\rm DS} = \frac{1}{2\pi 1\,{\rm MHz}\,1\,{\rm pF}} = 160\,{\rm k}\Omega$$

Therefore, the feedthrough is given by:

$$20 \log_{10} \frac{10 \,\mathrm{k}\Omega}{10 \,\mathrm{k}\Omega + 160 \,\mathrm{k}\Omega} = -25 \,\mathrm{dB}$$

#### Exercise 3.6

In this case, the output  $10 \,\mathrm{k}\Omega$  resistance is in parallel with the  $50 \,\Omega$   $R_{\mathrm{ON}}$  resistance. Their equivalent resistance is about  $50 \,\Omega$ . Similarly to the previous exercise, the feedthorugh is given by:

$$20\log_{10}\frac{50\,\Omega}{50\,\Omega+160\,k\Omega} = -70\,\mathrm{dB}$$

1.7. EXERCISE 3.7

### Exercise 3.7

Figure 1.2: Zero ohm  $R_{\rm ON}$ 

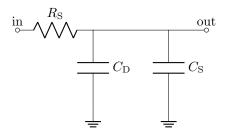
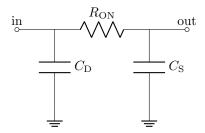


Figure 1.3:  $75 \Omega R_{ON}$ 



For this exercise we assume that the load resistance of  $100\,\mathrm{k}\Omega$  does not load the circuit.

(a) The circuit is that of Figure 1.2. Since  $C_D = C_S = C_T = 8 \,\mathrm{pF}$ , there is a single pole at the frequency  $f_P$ :

$$\boxed{f_{\rm p} = \frac{1}{4\pi R_{\rm S} C_{\rm T}} \approx 1\,{\rm MHz}}$$

(b) In this case the circuit is depicted in Figure 1.3. The circuit has one pole at DC and another pole at  $f_{\rm p}$ :

$$\boxed{f_{\rm p} = \frac{1}{2\pi R_{\rm ON} C_{\rm T}} \approx 265\,{\rm MHz}}$$

## Exercise 3.8

Figure 1.4: OFF-OFF

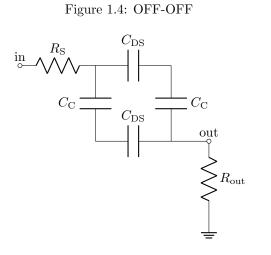
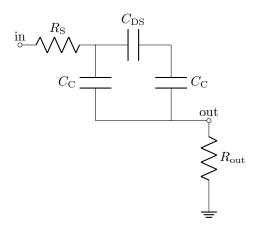


Figure 1.5: OFF-ON



1.8. EXERCISE 3.8

Figure 1.6: ON-OFF

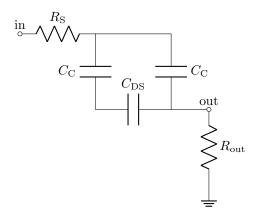
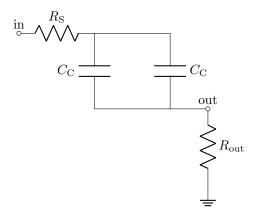


Figure 1.7: ON-ON



(a) In this case the reference circuit is depicted in Figure 1.4. The cross-coupling is given by:

$$20 \log_{10} \frac{R_{\text{out}}}{R_{\text{out}} + R_{\text{S}} + 0.5(X_{\text{C}} + X_{\text{DS}})} = -10.75 \,\text{dB}$$

being 
$$X_{\rm C}=\frac{1}{2\pi f\,C_{\rm C}}=320\,{\rm k}\Omega$$
 and  $X_{\rm DS}=\frac{1}{2\pi f\,C_{\rm DS}}=160\,{\rm k}\Omega$ 

(b) In this case the reference circuit is depicted in Figure 1.5. The cross-coupling is given by:

$$20\log_{10}\frac{R_{\text{out}}}{R_{\text{out}} + R_{\text{S}} + \frac{X_{\text{C}}(X_{\text{C}} + X_{\text{DS}})}{2X_{\text{C}} + X_{\text{DS}}}} = -9.6\,\text{dB}$$

- (c) In this case the reference circuit is depicted in Figure 1.6. The cross-coupling is the same as before
- (d) In this case the reference circuit is depicted in Figure 1.7. The cross-coupling is given by:

$$20\log_{10}\frac{R_{\text{out}}}{R_{\text{out}} + R_{\text{S}} + 0.5X_{\text{C}}} = -8.6\,\text{dB}$$

Exercise 3.9 TODO: write solution

Exercise 3.10 TODO: write solution

Exercise 3.11 TODO: write solution

Exercise 3.12 TODO: write solution

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